HIGH POWER ATTENUATOR CHIP 20 WATT

DATA SHEET	PART SERIES: HPCA54XX.00W1	SHEET 1 OF 2 Dwg 1009135	EN 16-0840 Revision A
FEATURES Small Footprint High Power Surface Mount Low VSWR Easy Installation Wide Attenuation Offe	APPLICATIONS Mobile Networks Broadcast High Power Amplifiers Isolators/Circulators Military		
GENERAL DESC	0	Alexandria A	united and Nited a

EMC Technology offers the widest selection of chip attenuators worldwide. Chip components are offered in Alumina, Aluminum Nitride, Beryllium Oxide, and CVD diamond for maximum performance.

ORDERING INFORMATION

Part Identifier: HPCA54XX.00W1

(XX) – dB Value

SPECIFICATIONS

1.0 ELECTRICAL

Nominal Impedance:	50 ohms
Frequency Range:	DC – 2.5 GHz
Attenuation Values Available:	1 – 20 in 1 dB increments
Attenuation Accuracy:	1 – 10 dB ± 0.5 dB
	20 dB ± 1.0 dB
Input Power CW:	20 Watts full rated power to 125°c, derated linearly to 0 watts at 150°c.
Peak Power:	50 watts for 10us pulse width @ 1% duty cycle.
VSWR:	DC – 1 GHz - 1.15:1
	1.1 – 2.5 GHz - 1.35:1

2.0 ENVIRONMENTAL

Operating Temperature:	-55°C to +150°C
Non-operating Temperature:	-65°C to +150°C

3.0 MARKING

Unit Marking:

"dB Value"

4.0 QUALITY ASSURANCE

Sample Inspect Per MIL-STD-105, Level II, 1.0% AQL.

Visual and Mechanical Inspection for Conformance to Outline Drawing

Measure Attenuation and VSWR

Data Retention - Standard

5.0 PACKAGING

Standard Packaging:

Tape and Reel



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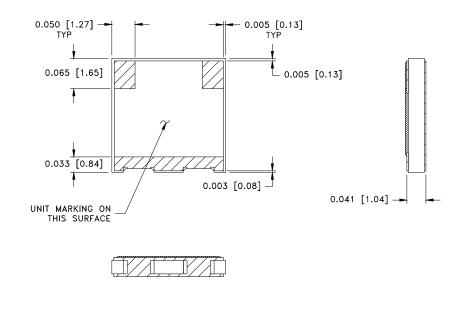
SHEET 2 OF 2 Dwg 1009135

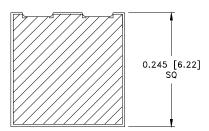
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6.0 MECHANICAL

Substrate: Resistive Film: Terminal Material: Metric Dimensions: Workmanship Beryllia Thick Film Thick Film, Nickel Barrier, Solder Plated Provided for reference only PER MIL-R-55342





Unless Otherwise Specified: TOLERANCE: $X.XXX = \pm 0.005$